

■ Features

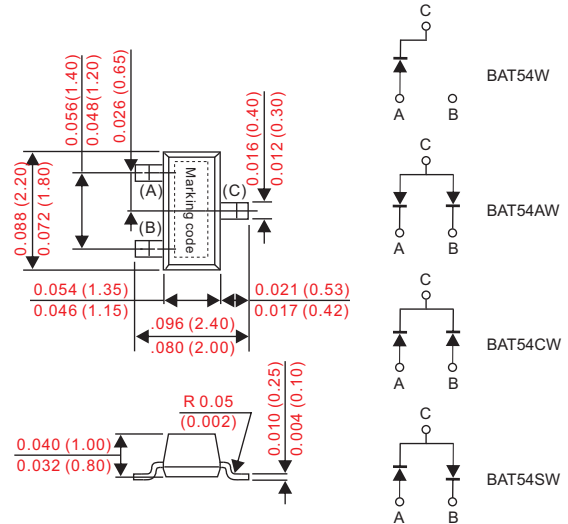
- Low current rectification and high speed switching.
- Small surface mount type.
- Up to 200mA current capability.
- Low forward voltage drop ($V_F = 1.00V$ typ. @100mA).
- Silicon epitaxial planar chip, metal silicon junction.
- High speed ($t_{rr} < 5$ ns)
- Suffix "G" indicates Halogen-free part, ex. BAT54WG.
- Lead-free parts for green partner, exceeds environmental standards of MIL-STD-19500 /228.

■ Mechanical data

- Epoxy: UL94-V0 rated flame retardant
- Case : Molded plastic, SOT-323
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Mounting Position : Any
- Weight : Approximated 0.006 gram

■ Outline

SOT-323



Dimensions in inches and (millimeters)

■ Maximum ratings and electrical characteristics

Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	BAT54W	BAT54AW	BAT54CW	BAT54SW	UNIT
Marking code		B4, KL5	B7, KL6	L3, KL7, 5C	B8, KL8	
Reverse Voltage	V_R	30				V
Forward Power Dissipation(1)	P_F	200				mW
		Derate above 25°C				$mW/^\circ C$
Forward Current(DC)	I_F	200				mA
Junction Temperature	T_J	+125				°C
Storage Temperature	T_{STG}	-55 ~ +150				°C
Characteristic	Symbol	MIN.	TYP.	MAX.	UNIT	
Reverse Breakdown Voltage	$I_{(BR)} = 10\mu A_{dc}$	$V_{(BR)}$	30		Vdc	
Reverse Voltage Leakage Current	$V_R = 25V_{dc}$	I_R	0.5	2.0	μA_{dc}	
Total Capacitance	$V_R = 1.0, f = 1.0MHz$	C_T	7.6	10	pF	
Forward Voltage	$I_F = 0.1mA_{dc}$ $I_F = 1.0mA_{dc}$ $I_F = 10mA_{dc}$ $I_F = 30mA_{dc}$ $I_F = 100mA_{dc}$	V_F	220 290 350 410 520	240 320 400 500 1000	mVdc	
Reverse Recovery Time	$I_F = I_R = 10mA_{dc}, V_R = 5.0V_{dc}, I_{R(REC)} = 1.0mA_{dc}, R_L = 100\Omega$	t_{rr}		5.0	nS	
Forward Current(DC)		I_F		200	mA _{dc}	
Repetitive Peak Forward Current		I_{FRM}		300	mA _{dc}	
Non-Repetitive Peak Forward Current	$t < 1.0s$	I_{FSM}		600	mA _{dc}	

1. FR-5 = 1.0 x 0.75 x 0.062 in.

Rating and characteristic curves

FIG.1-TYPICAL FORWARD CHARACTERISTICS

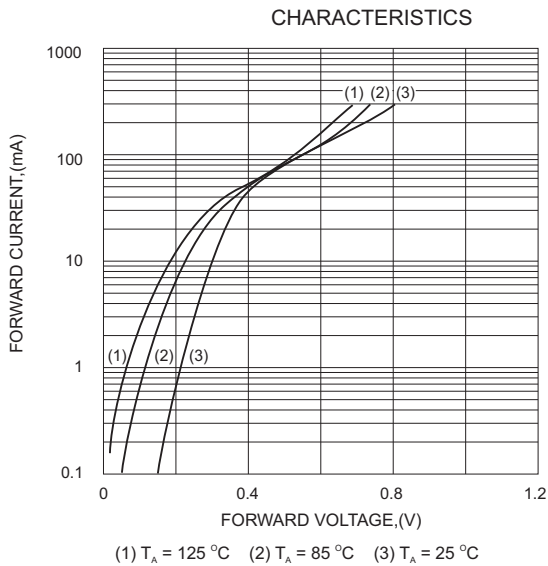


FIG.2 - Leakage Current CHARACTERISTICS

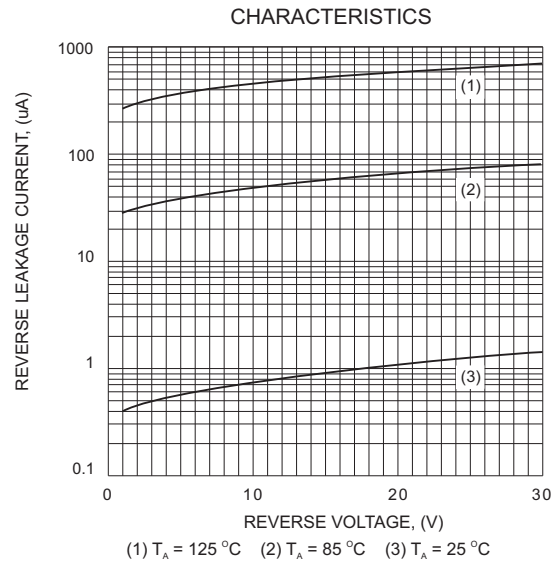
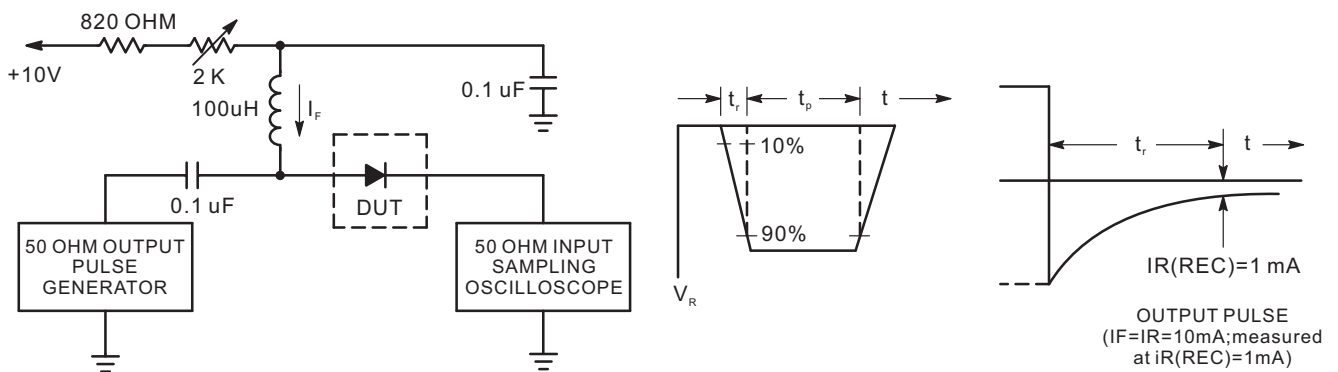
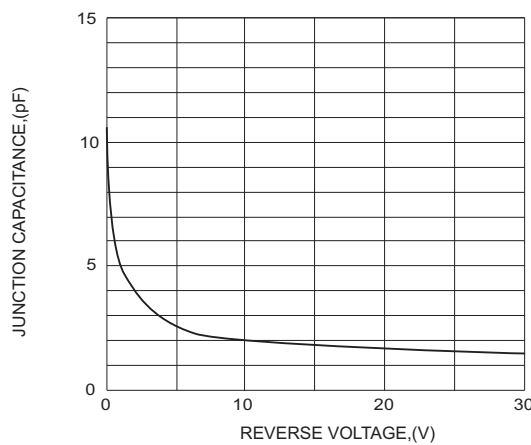


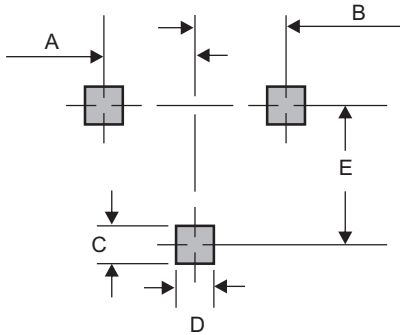
FIG.3-TYPICAL JUNCTION CAPACITANCE



- Notes :
1. A 2.0 Kohm variable resistor adjusted for a forward Current (I_F) of 10mA.
 2. Input pulse is adjusted so $iR(\text{peak})$ is equal to 10 mA.
 3. $t_p \gg t_{rr}$.

Recovery Time Equivalent Test Circuit

■ SOT-323 foot print



A	B	C	D	E
0.025 (0.65)	0.025 (0.65)	0.035 (0.90)	0.028 (0.70)	0.075 (1.90)

Dimensions in inches and (millimeters)

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